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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of

Takatomo SASAKI et al.

Attn: BOX PCT

Serial No. NEW

Docket No. 2001 1739A

Filed November 23, 2001

THE COMMISSIONER IS AUTHORIZED
TO CHARGE ANY DEFICIENCY IN THE
FEES FOR THIS PAPER TO DEPOSIT
ACCOUNT NO. 23-0975

METHOD AND APPARATUS FOR GROWING HIGH QUALITY SINGLE CRYSTAL

[Corresponding to PCT/JP00/03264]

[FEDERAL BUREAU OF INVESTIGATION]
Filed May 22, 2000]

PRELIMINARY AMENDMENT TO REDUCE PTO FILING FEE

**Assistant Commissioner for Patents,
Washington, DC 20231**

Sir:

Please amend the above-identified application as follows.

In the Claims:

Kindly amend claims 5 and 15 as follows.

5. (Amended) A method according to claim 3, wherein a single crystal of an oxide is grown.

15. (Amended) An apparatus for growing a single crystal of an oxide comprising the growing apparatus as claimed in claim 13.